1200-V Direct WBG Diode

Key Features:

- SiC performance
- Easy paralleling
- High current carrying capability
- Very low junction capacitance
- Highly stable V_F and Q_{RR} at elevated temperatures

Typical Applications:

- Soft switching topologies
- Secondary side rectification



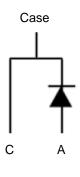
PRODUCT SUMMARY			
Vbr (V)	$V_{F}(V)$	IF(AV) (A)	
1200	1.8	10	



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ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Cathode-Anode Voltage		V _{BR}	1200	V	
Diode Forward Current ^a	T _C =25°C	I _{F(AV)}	10	А	
Single Pulse Forward Current ^b	T _C =25°C	I _{FSM}	50	А	
Joule Integral		i ² t	12	A²⋅s	
Power Dissipation ^a	T _C =25°C	PD	37	W	
Storage Temperature Range			-55 to 175	°C	
Operating Junction Temperature		TJ	-40 to 175	°C	

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient °	R _{θJA}	40	°C/W
Maximum Junction-to-Case	R _{eJC}	4.1	C/W

Notes

- a. Package Limited
- b. Pulse width limited by maximum junction temperature
- c. Surface Mounted on 1" x 1" FR4 Board.

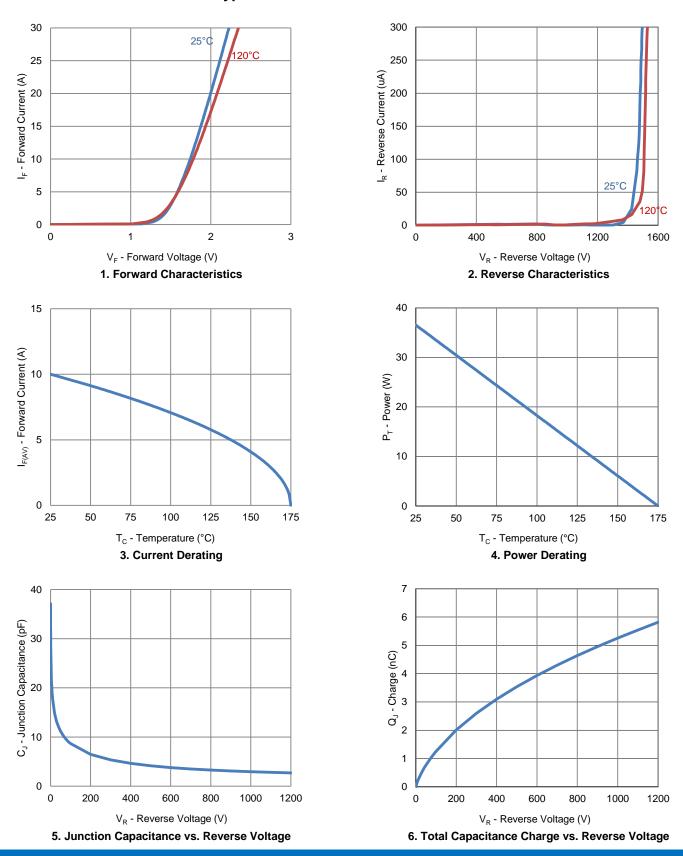
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
		Static				
	V _F	I _F = 10 A		1.8		V
Forward Voltage ^a	۷F	I _F = 10 A, T _J = 120°C		1.84	1.84	
Repetitive Peak Reverse Voltage	V _{RRM}	$T_{J} = -40^{\circ}C$ to 120°C	1200			V
Junction Capacitance	CJ	$V_{-} = 200 V_{-} V_{-} = 0.6 V_{-}$		6.3		pF
		V _R = 1200 V			2	uA
Reverse Leakage Current	I _R	V _R = 1200 V, T _J = 120°C			10	uA
		Dynamic ^b	•			
Reverse Recovery Time	T _{rr}			80		ns
Reverse Recovery Charge	Q _{rr}	I _F = 10 A, dl/dt = 100 A/us, T _J = 25°C		157		nC
Peak Recovery Current	I _{RRM}	15 - 25 0		3.3		А
Reverse Recovery Time	T _{rr}			75		ns
Reverse Recovery Charge	Q _{rr}	I _F = 10 A, dl/dt = 100 A/us, T _{.I} = 120°C		127		nC
Peak Recovery Current	I _{RRM}	1j = 120 0		2.8		А
Reverse Recovery Time	T _{rr}	L = 10.4 d / d t = 500.4 / u c		32		ns
Reverse Recovery Charge	Q _{rr}	I _F = 10 A, dl/dt = 500 A/us, T _J = 25°C		215		nC
Peak Recovery Current	I _{RRM}	15-25 0		11.2		А
Reverse Recovery Time	T _{rr}	L = 10.4 d / d t = 500.4 / u c		32		ns
Reverse Recovery Charge	Q _{rr}	I _F = 10 A, dl/dt = 500 A/us, T _{.I} = 120°C		193		nC
Peak Recovery Current	I _{RRM}	1 - 120 0		9.9		А

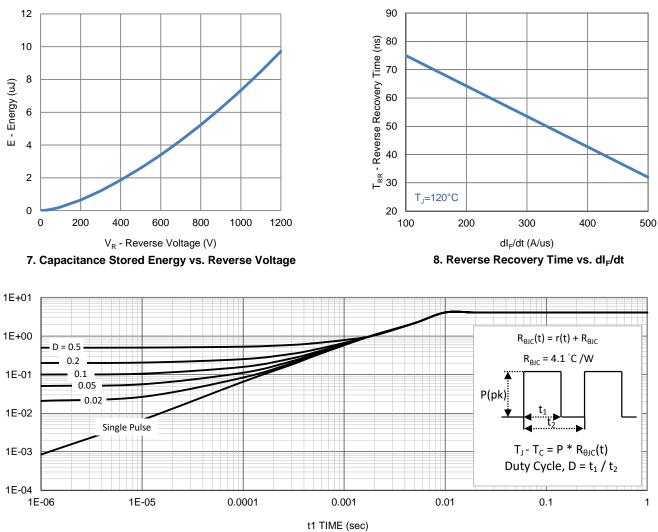
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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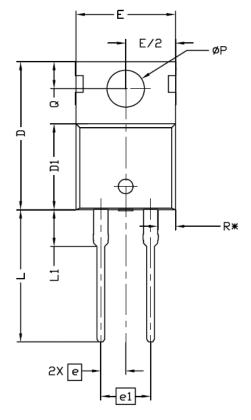
Typical Electrical Characteristics

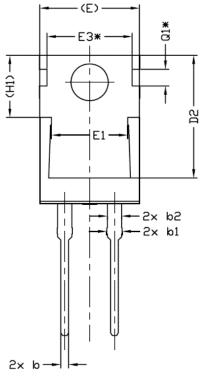


Typical Electrical Characteristics

9. Thermal Transient Junction to Ambient

Package Information





Γ	min	r+1	mhn	٦
Γ			1	

SYMBOL	DIMENSIONS			
STIVIBOL	MIN.	NOM.	MAX.	
А	4,24	4.44	4.64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
b	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.70	
с	0.40	0.50	0.60	
D	14.70	15.37	16.00	
D1	8,82	8,92	9.02	
D2	12.43	12.73	12.83	
E	9.96	10.16	10.36	
E1	6,86	7,77	8,89	
E3*	8.70REF.			
е	2.54BSC			
e1	5.08BSC			
H1	6.30 6.45		6,60	
L	13.47	13.72	13,97	
L1	3.60	3.80	4.00	
ØP	3.75	3.84	3.93	
Q	2,60	2,80	3,00	
Q1*	1.73REF.			
R*	1.82REF.			